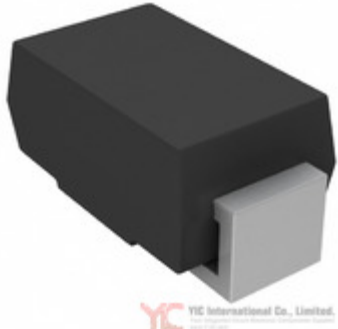
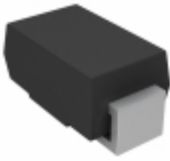

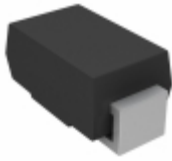
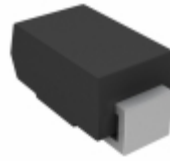
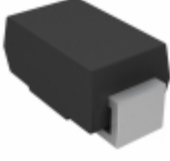

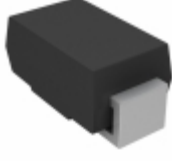

	<p>ESH1B-E3/61T</p>
	<p>Hersteller-Teilenummer: ESH1B-E3/61T</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 100V 1A DO214AC</p> <p>Datenblätter: 1.ESH1B-E3/61T.pdf 2.ESH1B-E3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 26200 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	ESH1B-E3/61T
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 100V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	26200 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	900mV @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 100V
Spannung - Sperr (Vr) (max)	100V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	25ns
Betriebstemperatur - Anschluss	-55°C ~ 175°C
Kapazität @ Vr, F	-
Verpackung	Tape & Reel (TR)

ESH1B-E3/61T ist neu im Original, Suche ESH1B-E3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ESH1B-E3/61T Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage ESH1B-E3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ESH1B-M3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1B M2G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1B-E3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1B-M3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>
 <p>ESH1B-E3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1BHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1B-M3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 100V 1A DO214AC</p>	 <p>ESH1B R3G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 1A DO214AC</p>

heiße Teile

Mehr

ESH1B-E3/61T	ESH1C-E3/61T	ESH1C-E3/61T	ESH1D-E3/61T	ESH1D-E3/61T
ESH1PB-E3/84A	ESH1PB-M3/84A	ESH1PB-M3/84A	ESH1PBHM3/84A	ESH1PBHM3/84A
ESH1PC-E3/84A	ESH1PC-M3/84A	ESH1PC-M3/84A	ESH1PCHM3/84A	ESH1PCHM3/84A
ESH1PD-E3/84A	ESH1PD-M3/84A	ESH1PD-M3/84A	ESH1PDHM3/84A	ESH1PDHM3/84A
ESH2B-E3/52T	ESH2B-E3/52T	ESH2C-01M3/5BT-HF	ESH2C-E3/52T	ESH2C-E3/52T
ESH2D-E3/52T	ESH2D-E3/52T	ESH2DHE3/52T	ESH2DHE3/52T	ESH2DHE3/5BT
ESH2DHE3/5BT	ESH2PB-E3/84A	ESH2PB-E3/84A	ESH2PB-M3/84A	ESH2PB-M3/84A
ESH2PBHM3/84A	ESH2PBHM3/84A	ESH2PC-E3/84A	ESH2PC-E3/84A	ESH2PC-M3/84A
ESH2PC-M3/84A	ESH2PCHM3/84A	ESH2PCHM3/84A	ESH2PD-M3/84A	ESH2PD-M3/84A
ESH2PDHM3/84A	ESH2PDHM3/84A	ESH3B-E3/57T	ESH3B-E3/57T	ESH3C-E3/57T

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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